

Nonlinear Anomalous Hall Effect for Néel Vector Detection

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Antiferromagnetic (AFM) spintronics exploits the Néel vector as a state variable for novel spintronic devices. Recent studies have shown that the fieldlike and antidamping spin-orbit torques (SOTs) can be used to switch the Néel vector in antiferromagnets with proper symmetries. However, the precise detection of the Néel vector remains a challenging problem. In this Letter, we predict that the nonlinear anomalous Hall effect (AHE) can be used to detect the Néel vector in most compensated antiferromagnets supporting the antidamping SOT. We show that the magnetic crystal group symmetry of these antiferromagnets combined with spin-orbit coupling produce a sizable Berry curvature dipole and hence the nonlinear AHE. As a specific example, we consider the half-Heusler alloy CuMnSb, in which the Néel vector can be switched by the antidamping SOT. Based on density-functional theory calculations, we show that the nonlinear AHE in CuMnSb results in a measurable Hall voltage under conventional experimental conditions. The strong dependence of the Berry curvature dipole on the Néel vector orientation provides a new detection scheme of the Néel vector based on the nonlinear AHE. Our predictions enrich the material platform for studying nontrivial phenomena associated with the Berry curvature and broaden the range of materials useful for AFM spintronics.

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Spintronics is a research field that studies the active control and detection schemes of the spin degrees of freedom in solid-state systems [1]. Over decades, novel phenomena have been discovered in the variety of ferromagnet-based layered structures, forming the core elements for spintronic applications. Recently, effort in the field has been deployed to enhance the device switching speed and reduce power consumption. In this regard, antiferromagnets are outstanding candidates to replace the widely used ferromagnets in the next generation of spintronic applications due to their robustness against magnetic perturbations, absence of stray fields, and ultrafast dynamics [2–6].

Recent findings have shown that the fieldlike spin-orbit torque (SOT) can be used to control the Néel vector in antiferromagnets with $\hat{P}\hat{T}$ symmetry (where \hat{P} is the space inversion symmetry and \hat{T} is the time reversal symmetry) [7–9], such as CuMnAs [10], Mn₂Au [11], and MnPd₂ [12]. The antidamping SOT can be used for Néel vector switching in globally noncentrosymmetric antiferromagnets, such as CuMnSb [8–10,13,14]. On the other hand, it is extremely difficult to detect the Néel vector in antiferromagnets using common magnetometers or magnetic resonance techniques due to the absent net magnetization and ultrafast magnetization dynamics [2]. Current experiments exploit the anisotropic magnetoresistance (AMR) effect to detect the Néel vector switching [2,10], where the readout speed is limited by its small magnitude [5]. Accurate

detection of the Néel vector orientation is possible using optical methods [15–17]. However, the specific requirements of these experimental techniques limit their device application. An efficient electric detection of the Néel vector using a conventional experimental setup would be desirable for a practical AFM spintronic device.

The anomalous Hall effect (AHE) [18,19] is a transport phenomenon driven by the Berry curvature $\mathbf{\Omega}$, a quantity inherent in the electronic band structure of a material [20–22]. Since $\mathbf{\Omega}$ is odd under time reversal symmetry \hat{T} , i.e., $\hat{T}\mathbf{\Omega}(\mathbf{k}) = -\mathbf{\Omega}(-\mathbf{k})$, where \mathbf{k} is the wave vector, the integral of $\mathbf{\Omega}$ over the full Brillouin zone (which determines the AHE) may be nonzero for materials with broken \hat{T} [20]. Since antiferromagnets have broken \hat{T} symmetry, they may support the nonvanishing AHE, which can be used for Néel vector detection. Recently, the AHE has been discovered in noncollinear antiferromagnets [Fig. 1(a)], such as Mn₃X (X = Ga, Ge, Sn, or Ir) [23–28] and Mn₃AN (A = Ga, Zn, Ag, or Ni) [29–31], and collinear antiferromagnets with specific arrangement of nonmagnetic atoms in the crystal lattice [Fig. 1(b)], such as CoNb₃S₆ [32–34]. These compounds hold, however, the net magnetization \mathbf{M} resulting from the weak canting of the local moments. This is due to no magnetic group symmetry operation $\hat{T}\hat{O}$ (\hat{O} is a crystal space group symmetry operation) enforcing \mathbf{M} to be zero, as follows from $\hat{T}\hat{O}\mathbf{M} = -\mathbf{M}$ [35].

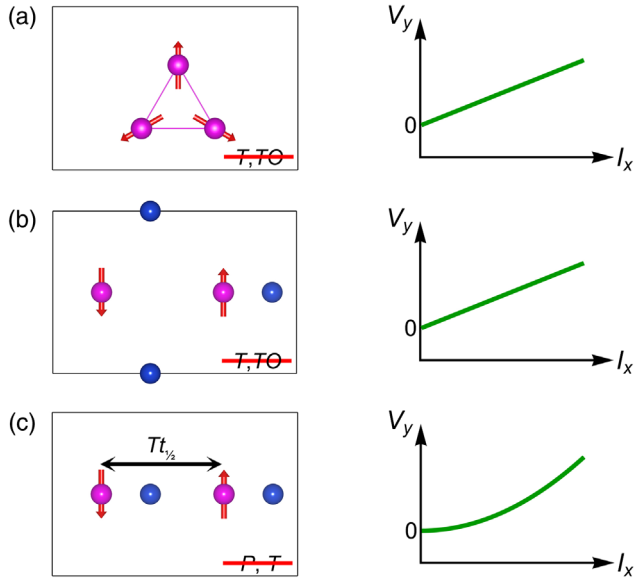


FIG. 1. (a) A noncollinear antiferromagnet with broken \hat{T} and absent $\hat{T}\hat{O}$ symmetry (\hat{O} is a crystal space group symmetry operation), such that $\hat{T}\hat{O}\mathbf{\Omega}(k') = -\mathbf{\Omega}(k)$ (left), resulting in a linear AHE (right). (b) A collinear antiferromagnet with a specific arrangement of nonmagnetic atoms in the crystal lattice, in which both \hat{T} and $\hat{T}\hat{O}$ symmetries are absent (left), resulting in a linear AHE (right). (c) A collinear antiferromagnet with broken \hat{P} and \hat{T} symmetries but preserved $\hat{T}\hat{\tau}_{1/2}$ symmetry (left), resulting in a nonlinear AHE (right).

Therefore, these canted antiferromagnets are not truly invisible to the magnetic perturbations. For example, the net magnetization of Mn_3Ge can be rotated by a small magnetic field, leading to reversal of the AHE [26]. To avoid such instabilities, the fully compensated antiferromagnets with $\mathbf{M} = 0$ are desirable for robust AFM spintronic devices. Zero magnetization requires, however, the $\hat{T}\hat{O}$ symmetry, which prohibits the AHE since $\mathbf{\Omega}$ is antisymmetric with respect to $\hat{T}\hat{O}$, i.e., $\hat{T}\hat{O}\mathbf{\Omega}(k') = -\mathbf{\Omega}(k)$ and $\hat{T}\hat{O}k' = k$. Thus, it is impossible to have a linear AHE in fully compensated antiferromagnets.

This problem can be solved with a recently discovered *nonlinear* AHE [36–42]. In contrast to the linear AHE, where the Hall voltage is linear to an applied electric field as found in numerous magnetic (i.e., \hat{T} broken) systems, the nonlinear AHE occurs in second-order response to an electric field as demonstrated for a certain class of nonmagnetic (i.e., \hat{T} invariant) materials. The nonlinear AHE requires broken \hat{P} symmetry and arises from the Berry curvature dipole \mathbf{D} , which generates a net anomalous velocity when the system is in a current-carrying state [36]. So far, however, the nonlinear AHE has been considered only for nonmagnetic materials where \hat{T} symmetry is preserved. Extending this concept to AFM materials where \hat{T} symmetry is broken is interesting and

desirable, as it would broaden a range of measurable properties useful for AFM spintronics.

In this Letter, we predict that the nonlinear AHE does exist in most compensated antiferromagnets supporting the electric control of the Néel vector by antidamping SOT. As a specific example, we consider the half-Heusler alloy CuMnSb and demonstrate, based on first-principles density-functional theory (DFT) calculations (see Supplemental Material [43]), that a polar axis and a combined $\hat{T}\hat{\tau}_{1/2}$ symmetry (where $\hat{\tau}_{1/2}$ is a translation of half the unit cell) support a sizable nonlinear AHE due to a finite Berry curvature dipole. Moreover, we predict a strong dependence of the Berry curvature dipole and hence the nonlinear AHE on the AFM Néel vector orientation, which can be used for the Néel vector detection in similar compounds.

The Berry curvature dipole density tensor \mathbf{d} is defined as $d_{bd} = -(\partial f_0 / \partial k_b) \Omega^d$, where k_b and Ω^d are Cartesian components of the wave vector and the Berry curvature, respectively, and f_0 is the equilibrium Fermi distribution function. It is odd under \hat{P} , and therefore, the nonlinear AHE in antiferromagnets requires a noncentrosymmetric structure. In fact, the condition is even more stringent and, similar to nonmagnetic systems, necessitates the presence of gyrotropic symmetry constraints [36,55,56]. We find that most compensated antiferromagnets supporting the antidamping SOT fulfill the symmetry requirements for the nonlinear AHE. Among the 123 noncentrosymmetric compensated antiferromagnets reported in the Bilbao MagnData database, there are 118 compounds with the magnetic space groups supporting the finite Berry curvature dipole [57,58].

For example, a polar axis and $\hat{T}\hat{\tau}_{1/2}$ symmetry [Fig. 1(c)] are sufficient for the nonlinear AHE to emerge in an antiferromagnet, due to \mathbf{d} being even under the $\hat{T}\hat{\tau}_{1/2}$ transformation, i.e., $\hat{T}\hat{\tau}_{1/2}\mathbf{d}(k) = \mathbf{d}(-k)$. This is the case for the half-Heusler alloy CuMnSb , an AFM metal supporting the antidamping SOT [8–10]. Figures 2(a) and 2(b) show the CuMnSb structure that belongs to the crystal space group $F\bar{4}3m$ [13,14,59]. Below the Néel temperature $T_N = 55$ K, a type-II collinear AFM order emerges, where the magnetic moments of the Mn atoms are parallel within the (111) plane but antiparallel between the successive (111) planes [Fig. 2(a)]. The Néel vector is pointed along the [111] direction. This AFM order lowers the symmetry, resulting in the magnetic space group R_73c [14]. The rhombohedral primitive cell of CuMnSb [Fig. 2(b)] contains threefold rotation \hat{C}_3 around the [111] direction and three glide mirror reflections $\hat{g}_{\bar{1}10}$, $\hat{g}_{\bar{1}01}$, and $\hat{g}_{0\bar{1}1}$, where $\hat{g}_l = \{\hat{M}_l | \hat{\tau}_{1/2}\}$ is mirror symmetry \hat{M}_l normal to vector \mathbf{l} combined with half a unit cell translation $\hat{\tau}_{1/2}$. In addition, below 34 K the Néel vector is canted toward the [110] direction by $\delta = 11^\circ$ [14,60]. This canting breaks the \hat{C}_3 , $\hat{g}_{\bar{1}01}$, and $\hat{g}_{0\bar{1}1}$ symmetries, leading to the magnetic space group C_c in which only $\hat{g}_{\bar{1}10}$ is

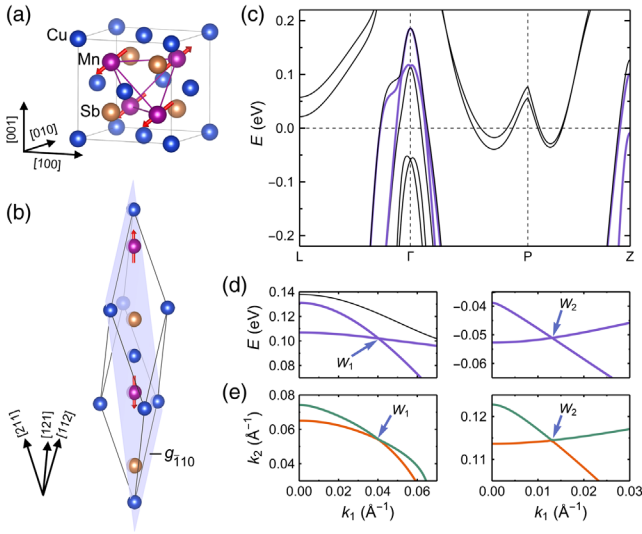


FIG. 2. (a),(b) The collinear AFM magnetic structure of CuMnSb shown in a conventional cubic unit cell (a) and a rhombohedral primitive cell (b). Red arrows denote the magnetic moments of Mn. The light blue plane denotes the glide plane \hat{g}_{110} . (c) The band structure of CuMnSb near E_F . (d) The band structures close to Weyl points W_1 with $k_2 = 0.054$ and $k_3 = 0.004 \text{ \AA}^{-1}$ (left) and W_2 with $k_2 = 0.115$ and $k_3 = 0.081 \text{ \AA}^{-1}$ (right). Here k_1 , k_2 , and k_3 are along the $[\bar{1}10]$, $[\bar{1}\bar{1}2]$, and $[111]$ directions in the cubic lattice. The purple lines in (c),(d) denote the two bands forming Weyl points. The horizontal dashed line indicates the Fermi energy. (e) The Fermi surfaces at $k_3 = 0.004 \text{ \AA}^{-1}$ and $E = 0.102 \text{ eV}$ (left) and at $k_3 = 0.081 \text{ \AA}^{-1}$ and $E = -0.051 \text{ eV}$ (right). The Weyl points are located at the intersection points of the Fermi surfaces.

preserved [14]. Both AFM phases of CuMnSb are polar and contain the $\hat{T}\hat{t}_{1/2}$ symmetry.

First, we investigate the AFM phase of CuMnSb without canting. Assuming the experimental lattice constant $a = 6.075 \text{ \AA}$, we find the calculated magnetic moment of $3.93 \mu_B/\text{Mn}$ consistent with the experimental value of $3.9(\pm 0.1) \mu_B/\text{Mn}$ [14]. Figure 2(c) shows the calculated band structure. There are six bands crossing the Fermi energy E_F , mostly contributed by $3d$ electrons of Mn [61] (Fig. S1 [43]). The four valence bands are very dispersive with the maximum around the Γ point, forming four hole pockets along the Γ -Z direction. The bands at the conduction band minimum are less dispersive, forming electron pockets near the edges of the top and bottom surfaces of the Brillouin zone (Fig. S1 [43]). There are multiple crossings and anticrossings in the band structure near E_F . For example, in Figs. 2(c) and 2(d) we show the band crossings by the second and third valence bands (purple lines). As seen from Fig. 2(d), there are two Weyl points at $E = 0.102 \text{ eV}$ (W_1) and $E = -0.051 \text{ eV}$ (W_2). The band crossings close to the Weyl points are strongly tilted. As is evident from Fig. 2(e), W_1 and W_2 are located at the touching points of the two Fermi pockets. This indicates

that W_1 and W_2 are type-II Weyl fermions [62,63]. By application of $\hat{T}\hat{t}_{1/2}$, \hat{C}_3 , and glide symmetry transformations to W_1 and W_2 , we obtain six pairs of W_1 and six pairs of W_2 Weyl fermions located in the central part of the Brillouin zone (Fig. S1 [43]).

Next, we discuss the nonlinear Hall response. Electric field $\mathbf{E}_c = \text{Re}\{\mathcal{E}e^{i\omega t}\}$ of amplitude \mathcal{E} and frequency ω produces nonlinear current $J_a = \text{Re}\{J_a^{(0)} + J_a^{(2)}e^{i2\omega t}\}$, where $J_a^{(0)} = \chi_{abc}^{(0)}\mathcal{E}_b\mathcal{E}_c^*$ describes the rectified current and $J_a^{(2)} = \chi_{abc}^{(2)}\mathcal{E}_b\mathcal{E}_c^*$ describes the second harmonic current. For a system with time reversal symmetry, the response coefficients are [36]

$$\chi_{abc}^{(0)} = \chi_{abc}^{(2)} = -\epsilon_{adc} \frac{e^3 \tau D_{bd}}{2\hbar^2(1+i\omega\tau)}, \quad (1)$$

where τ is the relaxation time, and D_{bd} is the Berry curvature dipole defined as

$$D_{bd} = \int \frac{d^3k}{(2\pi)^3} d_{bd} = - \int \frac{d^3k}{(2\pi)^3} \sum_n \frac{\partial E_{nk}}{\partial k_b} \Omega_{nk}^d \frac{\partial f_0}{\partial E_{nk}}. \quad (2)$$

Here E_{nk} is the energy of the n th band at the \mathbf{k} point. The Berry curvature of the n th band is given by [20,22]

$$\Omega_{nk}^d = i\epsilon_{abd} \sum_{m \neq n} \frac{\langle n | \frac{\partial H}{\partial k_a} | m \rangle \langle m | \frac{\partial H}{\partial k_b} | n \rangle}{(E_{nk} - E_{mk})^2}. \quad (3)$$

The factor $\partial E_{nk}/\partial k_b$ is odd under both \hat{P} and \hat{T} symmetries and Ω_{nk}^d is odd under \hat{T} and even under \hat{P} [22]. As a result, d_{bd} in Eq. (2) is even with respect to \hat{T} , leading to nonzero D_{bd} and a finite nonlinear AHE in a noncentrosymmetric system without magnetism. In an antiferromagnet like CuMnSb, the preserved $\hat{T}\hat{t}_{1/2}$ symmetry plays the same role as \hat{T} on $\partial E_{nk}/\partial k_b$ and Ω_{nk}^d , and the polar axis ensures a nonzero \mathbf{D} . Therefore, a finite D_{bd} can be also expected in such an antiferromagnet.

There is only one independent element of the \mathbf{D} tensor in the AFM phase without canting (see Supplemental Material [43] Table SII). For definiteness, we consider D_{xz} directly related to $J_y = \chi_{yxx}\mathcal{E}_x^2$, a transverse nonlinear Hall current along the y ($[010]$) direction produced by a longitudinal electric field along the x ($[100]$) direction. Figures 3(a) and 3(b) show the projection of D_{xz} on the k_1 - k_2 plane, at $E = 0.102 \text{ eV}$ [Fig. 3(a)] and $E = -0.051 \text{ eV}$ [Fig. 3(b)], which is obtained by integration $\int (dk_3/2\pi) d_{xz}$. According to Eq. (2), D_{xz} is a Fermi surface property, and thus only the Fermi pockets contribute to D_{xz} . We find that the contribution by the Fermi pockets from the conduction bands is negligible compared to those from the valence bands. This is due to the valence bands near their maximum having stronger dispersion, which leads to larger velocity

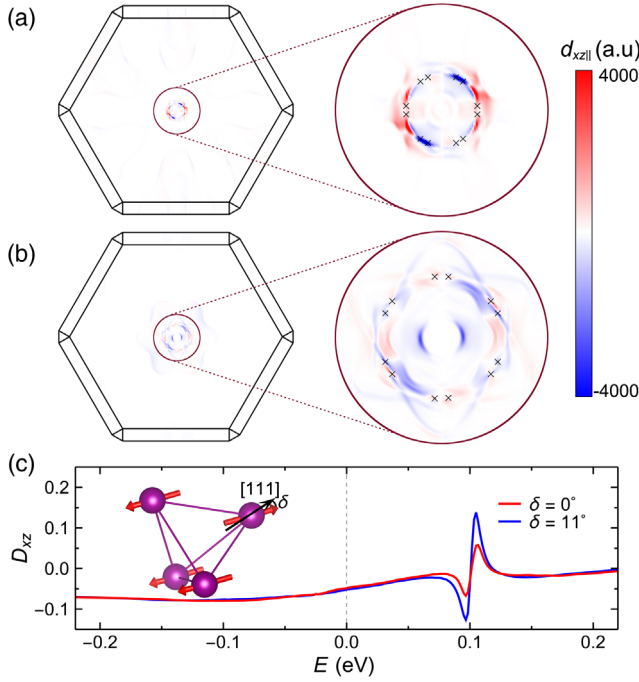


FIG. 3. (a),(b) The projections of the Berry curvature dipole on k_1 - k_2 plane at (a) $E = 0.102$ and (b) $E = -0.051$ eV. Black cross symbols denote position of the Weyl fermions. (c) The D_{xz} as a function of energy for the AFM phase without (red line) and with (blue line) canting of the Néel vector. (Inset) Schematic showing the canting.

$v_x = \partial E_{nk} / \partial k_x$ [Fig. 2(c)]. On the other hand, the gaps between the valence bands are very small near E_F , which leads to larger Ω_{nk}^z according to Eq. (3). Therefore, as seen from the energy dependence of D_{xz} in Fig. 3(c), the magnitude of D_{xz} increases with energy decreasing, due to the increase of the volume of the central Fermi surfaces from the valence bands. The calculated D_{xz} is about -0.048 at E_F , and can be enhanced to -0.080 by proper doping [Fig. 3(c)]. These values are comparable to those obtained for nonmagnetic metals [38,39].

We note that the contributions of the Weyl fermions W_1 and W_2 to D_{xz} are different. The states near W_1 dominate D_{xz} around $E = 0.102$ eV, as shown in Fig. 3(a) and Supplemental Material Fig. S4 [43], leading to the anomaly in the D_{xz} curve at this energy [Fig. 3(c)]. On the other hand, there is no pronounced contributions from W_2 [Fig. 3(b)] due to the weak tilting of the Weyl cones [43], which suppresses the anomaly in the D_{xz} curve at $E = -0.051$ eV [Fig. 3(c)]. We note that the calculated D_{xz} at E_F is independent of W_1 and W_2 , since \mathbf{D} is the Fermi surface property, and W_1 and W_2 lie away from E_F . The suitable symmetry, dispersive band structure, and strong spin-orbit coupling are sufficient to produce a sizable \mathbf{D} at E_F .

At low temperature, the Néel vector is tilted toward the $[110]$ direction by $\delta = 11^\circ$ [14]. This weak canting leads to tiny changes of the band structure (Fig. S2 [43]).

Nevertheless, breaking the \hat{C}_3 , $\hat{g}_{\bar{1}01}$, and $\hat{g}_{0\bar{1}1}$ symmetries alters the number and the positions of the Weyl fermions (Fig. S2 [43]). The energy dependence of D_{xz} in this AFM phase is generally similar to that in the AFM phase without canting, except for sharper peaks above E_F due to the different distribution of the Weyl points [Fig. 3(c) and Supplemental Material Fig. S2 [43]]. Moreover, the change of symmetry influences the \mathbf{D} tensor [43], resulting in different magnitudes of D_{xy} and D_{xz} (Supplemental Material Table SII [43]). This difference can be further enhanced by stronger canting. For example, for the canting angle of $\delta = 90^\circ$ (similar to that in a half-Heusler alloy GdMnBi [64]), we find $D_{xy} = 0.072$ being much larger than D_{xz} (Table SII [43]). Since D_{xy} is related to the Hall voltage V_z , the large difference between D_{xy} and D_{xz} leads to different nonlinear Hall responses in the y and z directions, which can be used to detect Néel vector canting.

The sensitivity of the Berry curvature dipole to the Néel vector orientation implies that the nonlinear AHE can be used to detect it. The type-II AFM order with the Néel vector normal to the (111) planes in CuMnSb is energetically identical to that normal to the $(\bar{1}\bar{1}1)$, $(1\bar{1}\bar{1})$, or $(\bar{1}\bar{1}\bar{1})$ planes. These orders are expected to have different signs of the transverse and vertical Hall voltage [Fig. 4(a)]. For example, switching the Néel vector from (111) to $(\bar{1}\bar{1}\bar{1})$ is equivalent to the C_2 rotation around the $[001]$ direction. This operation changes the sign of D_{xz} but does not affect D_{xy} . Therefore, V_y is reversed and V_z does not change by this switching. Figure 4(b) schematically shows a SOT device for such switching. The Néel vector is switched by the antidamping SOT using current J_w (usually $\sim 10^7$ – 10^8 A/cm²). The switched Néel vector can be detected by measuring the Hall voltage V_y and V_z , as

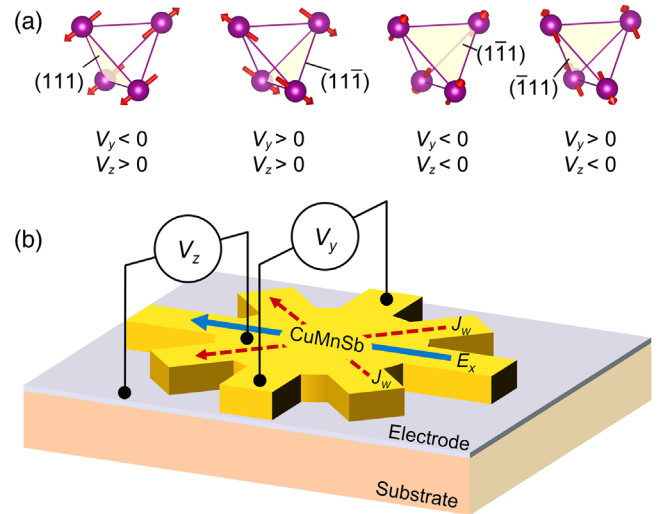


FIG. 4. (a) The signs of the Hall voltages V_y and V_z for different AFM orders of CuMnSb. (b) A spin-orbit torque device where the AFM orders of CuMnSb are switched using the antidampinglike SOT generated by the writing current J_w .

shown in Fig. 4(a). Considering a sample of $100\ \mu\text{m}$ in length and typical reading current $J_x = 5 \times 10^6\ \text{A}/\text{cm}^2$, the Hall voltage of $V_y \sim 14\text{--}90\ \mu\text{V}$ in the dc limit is estimated [43], which is well within the capacity of experiments.

Importantly, a high frequency electric field can generate a steady rectified component and the second harmonic component in the Hall current. This allows us to distinguish the nonlinear AHE signal from the noise induced by the input first harmonic electric field. This feature implies the possible measurement of nonlinear AHE generated by high frequency fields, such as picosecond pulses using the noncontact technology, which is very promising for efficient ultrafast detection [40,65,66].

The nonlinear AHE is expected to exist in a broad range of AFM materials, in which the Néel vector can be controlled by the antidamping SOT. In addition to CuMnSb, AFM metals PdMnTe [67] and $\text{Ca}_3\text{Ru}_2\text{O}_7$ [68–70] are promising candidates to host a large nonlinear AHE due to the strong spin-orbit coupling induced by the heavy metal elements.

In conclusion, we have predicted that the nonlinear AHE exists in most compensated antiferromagnets, supporting the electric control of the Néel vector by antidamping SOT. As an example, we have considered the half-Heusler alloy CuMnSb and showed that this antiferromagnet has a large Berry curvature dipole resulting in a sizable nonlinear AHE. The strong dependence of the Berry curvature dipole on the Néel vector orientation provides a new detection scheme of the AFM order, which is useful for AFM spintronics. We hope therefore that our theoretical predictions will motivate experimentalists to explore the nonlinear AHE in antiferromagnets.

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